# multicomp



## **Description:**

Complementary silicon power transistors. The MJ15004 power transistors designed for high power audio, disk head positioners and other linear applications.

## Features:

- High safe operating area (100% tested) 5A at 50V
- For low distortion complementary designs
- High DC current gain = h<sub>FF</sub> = 25 (min.) at IC = 5A DC
- Pb-free packages

#### **Maximum Ratings**

Rating	Symbol	Value	Unit	
Collector-Emitter Voltage	V <sub>CEO</sub>	140		
Collector-Base Voltage	V <sub>CBO</sub>	140	V DC	
Emitter-Base Voltage	V <sub>EBO</sub>	5		
Collector Current-Continuous	Ι <sub>C</sub>	20		
Base Current-Continuous	Ι <sub>Β</sub>	5	A DC	
Emitter Current-Continuous	Ι <sub>Ε</sub>	25		
Total Power Dissipation at T <sub>C</sub> = 25°C Derate above 25°C	P <sub>D</sub>	250 1.43	W W/°C	
Operating and Storage Junction Temperature Range	T <sub>J</sub> , T <sub>Stg</sub>	-65 to +200	°C	

#### **Thermal Characteristics**

Characteristic	Symbol	Max.	Unit
Thermal Resistance Junction to Case	R <sub>ejc</sub>	0.7	°C/W
Max. Lead Temperature for Soldering Purposes 1/16 inches from Case for ≤10 seconds	Τ <sub>L</sub>	265	°C

Max. ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

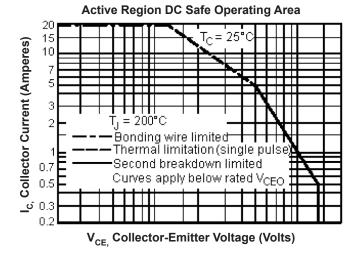
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Characteristic	Symbol	Min.	Max.	Unit
Off Characteristics		•	•	
Collector-Emitter Sustaining Voltage (1) ( $I_C = 200$ mA DC, $I_B = 0$ )	V <sub>CEO (sus)</sub>	140	-	V DC
Collector Cut off Current ( $V_{CE}$ = 140V DC, $V_{BE (off)}$ = 1.5V DC) ( $V_{CE}$ = 140V DC, $V_{BE (off)}$ = 1.5V DC, $T_{C}$ = 150°C)	I <sub>CEX</sub>	-	100 2	µA DC mA DC
Collector Cut off Current ( $V_{CE}$ = 140V DC, I <sub>B</sub> = 0)	I <sub>CEO</sub>	-	250	μA DC
Emitter Cut off Current ( $V_{EB} = 5V DC$ , $I_C = 0$ )	I <sub>EBO</sub>	-	100	
Second Breakdown		•	•	
Second Breakdown Collector Current with Base Forward Biased ( $V_{CE}$ = 50V DC, t = 1s (non repetitive) ( $V_{CE}$ = 100V DC, t = 1s (non repetitive)	I <sub>S/b</sub>	5 1	-	A DC
On Characteristics	•	•		•
DC Current Gain ( $I_C$ = 5A DC, $V_{CE}$ = 2V DC	h <sub>FE</sub>	25	150	-
Collector-Emitter Saturation Voltage ( $I_C = 5A DC$ , $I_B = 0.5A DC$ )	V <sub>CE (sat)</sub>	-	1	- V DC
Base-Emitter On Voltage ( $I_C = 5A DC$ , $V_{CE} = 2V DC$ )	V <sub>BE (on)</sub>	-	2	
Dynamic Characteristics				
Current-Gain Bandwidth Product ( $I_C = 0.5A DC$ , $V_{CE} = 10V DC$ , $f_{test} = 0.5MHz$ )	f <sub>T</sub>	2	-	MHz
Output Capacitance (V <sub>CB</sub> = 10V DC, I <sub>E</sub> = 0, f <sub>test</sub> = 1MHz)	C <sub>OB</sub>	-	1,000	pF

1. Pulse Test: Pulse Width = 300µs, Duty Cycle ≤2%



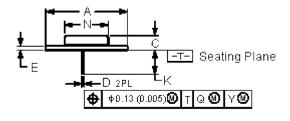
www.element14.com www.farnell.com www.newark.com There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate  $I_C - V_{CE}$  limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

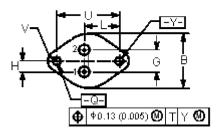
The data is based on  $T_{J (pk)} = 200^{\circ}C$ ;  $T_C$  is variable depending on conditions. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.





## Dimensions





#### Dimensions Min. Max. 1.55 (39.37) Reference А В 1.05 (26.67) С 0.25 (6.35) 0.335 (8.51) D 0.038 (0.97) 0.043 (1.09) Е 0.055 (1.4) 0.07 (1.77) G 0.43 (10.92) BSC Н 0.215 (5.46) BSC Κ 0.44 (11.18) 0.48 (12.19) L 0.665 (16.89) BSC Ν 0.83 (21.08) 0.165 (4.19) Q 0.151 (3.84) U 1.187 (30.15) BSC V 0.131 (3.33) 0.188 (4.77)

Dimensions : Inches (Millimetres)

#### Pin Configuration:

Pin 1. Base

2. Emitter

Collector (Case)

#### Part Number Table

Description	Part Number	
Transistor, PNP, TO-3	MJ15004	

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